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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/743,771	12/24/2003	Yasuo Inoue	57454-981	9456
7590 06/30/2005				
McDermott, Will & Emery 600 13th Street, N.W. Washington, DC 20005-3096			EXAMINER WARREN, MATTHEW E	
			ART UNIT 2815	PAPER NUMBER

DATE MAILED: 06/30/2005

Please find below and/or attached an Office communication concerning this application or proceeding.

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Office Action Summary	Application No. 10/743,771	Applicant(s) INOUE ET AL.	
	Examiner Matthew E. Warren	Art Unit 2815	

-- The MAILING DATE of this communication appears on the cover sheet with the correspondence address --

Period for Reply

A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION.

- Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.
- If the period for reply specified above is less than thirty (30) days, a reply within the statutory minimum of thirty (30) days will be considered timely.
- If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.
- Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).

Status

- 1) ☒ Responsive to communication(s) filed on 14 April 2005.
- 2a) ☒ This action is **FINAL**. 2b) ☐ This action is non-final.
- 3) ☐ Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11, 453 O.G. 213.

Disposition of Claims

- 4) ☒ Claim(s) 34-45 is/are pending in the application.
- 4a) Of the above claim(s) _____ is/are withdrawn from consideration.
- 5) ☐ Claim(s) _____ is/are allowed.
- 6) ☒ Claim(s) 34-45 is/are rejected.
- 7) ☐ Claim(s) _____ is/are objected to.
- 8) ☐ Claim(s) _____ are subject to restriction and/or election requirement.

Application Papers

- 9) ☐ The specification is objected to by the Examiner.
- 10) ☐ The drawing(s) filed on _____ is/are: a) ☐ accepted or b) ☐ objected to by the Examiner.
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).
- 11) ☐ The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.

Priority under 35 U.S.C. § 119

- 12) ☐ Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).
- a) ☐ All b) ☐ Some * c) ☐ None of:
1. ☐ Certified copies of the priority documents have been received.
2. ☐ Certified copies of the priority documents have been received in Application No. _____.
3. ☐ Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).
- * See the attached detailed Office action for a list of the certified copies not received.

Attachment(s)

- | | |
|---|---|
| 1) <input type="checkbox"/> Notice of References Cited (PTO-892) | 4) <input type="checkbox"/> Interview Summary (PTO-413) |
| 2) <input type="checkbox"/> Notice of Draftsperson's Patent Drawing Review (PTO-948) | Paper No(s)/Mail Date. _____ |
| 3) <input type="checkbox"/> Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08) | 5) <input type="checkbox"/> Notice of Informal Patent Application (PTO-152) |
| Paper No(s)/Mail Date _____ | 6) <input type="checkbox"/> Other: _____ |

DETAILED ACTION

This Office Action is in response to the Amendment filed on April 14, 2005.

Claim Rejections - 35 USC § 112

The following is a quotation of the second paragraph of 35 U.S.C. 112:

The specification shall conclude with one or more claims particularly pointing out and distinctly claiming the subject matter which the applicant regards as his invention.

Claims 34-45 are rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention.

In claim 34, the limitation of "a second isolation region including a second insulating film being provided between said first active region and said second active region in contact with said insulating layer..." is indefinite. Its grammatical structure makes it difficult to determine if the second isolation region is in contact with the insulating layer or if the second active region is in contact with the insulating layer. From the applicant's arguments it seems that it is meant that the second isolation region is in contact with the insulating layer. Therefore, for purposes of examination, the limitation will be understood to mean "a second isolation region including a second insulating film being provided between said first active region and said second active region, the second isolation region also in contact with said insulating layer."

Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless –

(e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.

Claims 34, 35, and 45, as far as understood, are rejected under 35 U.S.C. 102(e) as being anticipated by Kumagai (US 5,397,906).

In re claim 34, Kumagai shows (figs. 5A-5C) a semiconductor layer (1') arranged on a main surface of a semiconductor substrate (1) with an insulating layer (14) between said semiconductor substrate and said semiconductor layer, a plurality of MOS field effect transistors (6) of a first conductivity type at a first active region (Q_N) of said semiconductor layer, and an MOS field effect transistor (3) of a second conductivity type at a second active region (Q_P) of said semiconductor layer. Kumagai shows in figure 5C that said first active region comprises a first isolation region including a first insulating layer (FOX region 13 between adjacent transistors 6), said plurality of MOS field effect transistors of the first conductivity type being isolated from each other by said first isolation region. A second isolation region including a second insulating film (FOX region 13 separating regions Q_N and Q_P) is provided between said first active region and said second active region. In figures 7A-7C, Kumagai shows that the second isolation region (13) is in contact with the insulation layer (14). The first active region

and said second active region are electrically isolated from each other by said second isolation region.

In re claim 35, Kumagai shows (fig. 5C) a lower semiconductor layer (portion of P⁻) remains under said first insulating film in said first isolation region, each portion of said semiconductor layer provided in said first active region being electrically connected with each other integrally by said lower semiconductor layer.

In re claim 45, Kumagai shows (fig. 5A-5C) an electrode (Vcc or GND) is provided in respective said semiconductor layer of said first active region and said second active region, and said electrode is held at a ground potential or a predetermined fixed potential.

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negated by the manner in which the invention was made.

Claims 36 and 37 are rejected under 35 U.S.C. 103(a) as being unpatentable over Kumagai (US 5,397,906) as applied to claims 34 and 35 above, and further in view of Ogoh (US 5,436,482).

In re claim 36, Kumagai shows all of the elements of the claims except the field shield gate electrode provided above the first insulating layer, which Ogoh discloses (col. 11, lines 55-64). Therefore it would have been obvious to one of ordinary skill in

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the art at the time the invention was made to modify the isolation region of Kumagai by adding a field shield gate electrode as taught by Ogoh to provide additional isolation of active regions.

In re claim 37, Ogoh also discloses (col. 11, lines 55-65) that the insulating film in the first isolation region is an oxide film made by local oxidation of said semiconductor layer. However, such a limitation is a "product by process" limitation. A "product by process" claim is directed to the product per se, no matter how actually made, In re Hirao, **190 USPQ 15 at 17**(footnote 3). See also in re Brown, **173 USPQ 685**; In re Luck, **177 USPQ 523**; In re Fessmann, **180 USPQ 324**; In re Avery, **186 USPQ 116** in re Wertheim, **191 USPQ 90 (209 USPQ 254** does not deal with this issue); and In re Marosi et al, **218 USPQ 289** final product per se which must be determined in a "product by, all of" claim, and not the patentability of the process, and that an old or obvious product, whether claimed in "product by process" claims or not. Note that Applicant has the burden of proof in such cases, as the above case law makes clear. "Even though product-by- process claims are limited by and defined by the process, determination of patentability is based upon the product itself. The patentability of a product does not depend on its method of production. If the product in product-by-process claim is the same as or obvious from a product of the prior art, the claim is unpatentable even though the prior product is made by a different process." In re Thorpe, **227 USPQ 964, 966** (Fed. Cir. 1985)(citations omitted).

Claims 38-40 are rejected under 35 U.S.C. 103(a) as being unpatentable over Kumagai (US 5,397,906) as applied to claims 34 and 35 above, and further in view of Nagakubo et al. (US 4,478,655).

In re claims 38 and 39, Kumagai shows all of the elements of the claims except the second insulating film in said second isolation region is a replacement for said semiconductor layer in said second isolation region completely removed or that the second isolation region is an oxidation of all said semiconductor layer in said second isolation region. Nagakubo et al. shows (fig. 6) a semiconductor layer (132) formed on an insulating substrate (131). The active regions of the layer are isolated and divided by an insulating film 110 that is a replacement for the semiconductor layer. The semiconductor layer is completely removed in that the insulating film is an oxidation of all of the semiconductor layer. With this configuration, the active layers can be completely separated into island substrate regions (col. 11, lines 20-63). Therefore, it would have been obvious to one of ordinary skill in the art at the time the invention was made to modify the second isolation region of Kumagai by forming the insulating film completely through the semiconductor layer as taught by Nagakubo to completely separate the active layers into island substrate regions.

In re claim 40, Nagakubo shows (fig. 6) that a portion of said second insulating film in said second isolation film (110) is an insulating film identical to an interlayer insulating film (121) provided above said MOS field effect transistor of the first conductivity type or said MOS field effect transistor of the second conductivity type. The isolation film and interlayer insulating film are both made of silicon oxide.

Claims 41-44 are rejected under 35 U.S.C. 103(a) as being unpatentable over Kumagai (US 5,397,906) in view of Nagakubo et al. (US 4,478,655) as applied to claims 34, 35, and 38 above, and further in view of Yatsuda et al (US 4,668,970).

In re claim 41, Kumagai and Nagakubo show all of the elements of the claims except the second insulating film having a plurality of insulating films stacked. Yatsuda et al. shows (fig. 4b) an isolation region (7) being a multilayered insulating film having a plurality of insulating films (7, 40, 5, 40') stacked. A field shield electrode (5) is formed on the isolation film to provide a tunable isolation region. Therefore, it would have been obvious to one of ordinary skill in the art at the time the invention was made to modify the isolation region of Kumagai and Nagakubo by forming a multilayered insulation film as taught by Yatsuda to provide adequate isolation for a semiconductor active region.

In re claims 42-44, the limitations of the claims pertain to "product by process." See the explanation above concerning "product by process" limitations.

Response to Arguments

Applicant's arguments filed with respect to claims 34-45 have been fully considered but they are not persuasive. The applicant primarily asserts that Kumagai does not show all of the elements of the claims, particularly the added limitation of the second isolation region including a second insulating film and being provided between the first active region and the second active region and in contact with the insulating layer. The examiner believes that Kumagai shows all of the limitations of the claims and that the 102 rejection is still proper. As stated in the 102 rejection above, Kumagai

shows in an alternate embodiment (figs. 7A-7C) that the second isolation region (13) is in contact with the insulating layer (14) to completely separate the first and second active regions. The arguments for Nagakubo not showing such a limitation are moot since Kumagai already teaches such a structure. Furthermore, Nagakubo's invention is analogous because both inventions pertain to a semiconductor device formed on an SOI substrate. Nagakubo was primarily cited to cure the deficiencies of claims 38-40 and show that the semiconductor layer is completely removed in that the insulating film is an oxidation of all of the semiconductor layer to completely separate the active regions into different islands. Whether the active regions of Nagakubo are different or not is irrelevant because Kumagai already teaches that the island regions have different conductivity types. Kumagai only lacked the specific teaching of the complete removal or oxidation of the semiconductor region and Nagakubo was cited to cure that deficiency. Therefore, the cited art shows all of the elements of the claims and this action is made final.

Conclusion

THIS ACTION IS MADE FINAL. Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire **THREE MONTHS** from the mailing date of this action. In the event a first reply is filed within **TWO MONTHS** of the mailing date of this final action and the advisory action is not mailed until after the end of the **THREE-MONTH** shortened statutory period, then the

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shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the mailing date of this final action.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Matthew E. Warren whose telephone number is (571) 272-1737. The examiner can normally be reached on Mon-Thur and alternating Fri 9:00-5:00pm.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Tom Thomas can be reached on (571) 272-1664. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see <http://pair-direct.uspto.gov>. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

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June 27, 2005

Tom Thomas
TOM THOMAS
SUPERVISORY PATENT EXAMINER